

<u>Si/SiC Hybrid Module</u> – EliteSiC, 3-channel, 1200 V IGBT + SiC Boost, 80 A IGBT

IGBT + SiC Boost, 80 A IGBT and 20 A SiC Diode, Q1 Package

NXH240B120H3Q1PG, NXH240B120H3Q1PG-R, NXH240B120H3Q1SG

The NXH240B120H3Q1PG is a case power module containing a three channel BOOST stage. The integrated field stop trench IGBTs and SiC Diodes provide lower conduction losses and switching losses, enabling designers to achieve high efficiency and superior reliability.

Features

- 1200 V Ultra Field Stop IGBTs
- Low Reverse Recovery and Fast Switching SiC Diodes
- Low Inductive Layout
- Press-fit Pins
- Thermistor

Typical Applications

- Solar Inverters
- ESS

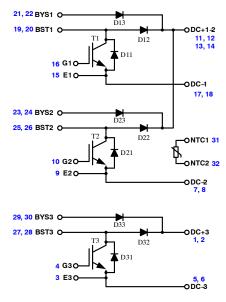
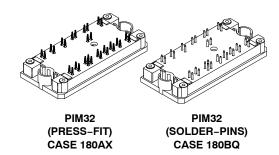
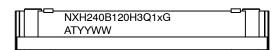


Figure 1. Schematic Diagram



MARKING DIAGRAM



NXH240B120H3Q1xG = Specific Device Code x = P or S

G = Pb-Free Package

AT = Assembly & Test Site Code YYWW = Year and Work Week Code

PIN ASSIGNMENTS



ORDERING INFORMATION

See detailed ordering and shipping information in the dimensions section on page 12 of this data sheet.

Table 1. MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
GBT (T1, T2, T3)			
Collector-Emitter Voltage	V _{CES}	1200	V
Gate-Emitter Voltage	V _{GE}	±20	V
Continuous Collector Current @ T _h = 80°C (T _J = 175°C)	I _C	68	А
Pulsed Collector Current (T _J = 175°C)	I _{Cpulse}	204	Α
Maximum Power Dissipation (T _J = 175°C)	P _{tot}	158	W
Minimum Operating Junction Temperature	T _{JMIN}	-40	°C
Maximum Operating Junction Temperature	T _{JMAX}	150	°C
PROTECTION DIODE (D11, D21, D31)	<u> </u>		
Peak Repetitive Reverse Voltage	V_{RRM}	1200	V
Continuous Forward Current @ T _h = 80°C (T _J = 150°C)	I _F	30	А
Repetitive Peak Forward Current (T _J = 150°C)	I _{FRM}	120	А
Maximum Power Dissipation (T _J = 150°C)	P _{tot}	44	W
Minimum Operating Junction Temperature	T _{JMIN}	-40	°C
Maximum Operating Junction Temperature	T _{JMAX}	150	°C
SILICON CARBIDE BOOST DIODE (D12, D22, D32)			•
Peak Repetitive Reverse Voltage	V_{RRM}	1200	V
Continuous Forward Current @ T _h = 80°C (T _J = 175°C)	I _F	25	А
Repetitive Peak Forward Current (T _J = 175°C)	I _{FRM}	75	А
Maximum Power Dissipation (T _J = 175°C)	P _{tot}	73	W
Minimum Operating Junction Temperature	T _{JMIN}	-40	°C
Maximum Operating Junction Temperature	T _{JMAX}	175	°C
BYPASS DIODE (D13, D23, D33)			•
Peak Repetitive Reverse Voltage	V_{RRM}	1200	V
Continuous Forward Current @ T _h = 80°C (T _J = 150°C)	I _F	42	А
Repetitive Peak Forward Current (T _J = 150°C)	I _{FRM}	126	А
Maximum Power Dissipation (T _J = 150°C)	P _{tot}	50	W
Minimum Operating Junction Temperature	T _{JMIN}	-40	°C
Maximum Operating Junction Temperature	T _{JMAX}	150	°C
HERMAL PROPERTIES			-
Storage Temperature range	T _{stg}	-40 to 150	°C
NSULATION PROPERTIES	•		•
			1/
Isolation test voltage, t = 1 sec, 60 Hz	V _{is}	3000	V_{RMS}

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality

Table 2. RECOMMENDED OPERATING RANGES

Rating	Symbol	Min	Max	Unit
Module Operating Junction Temperature	T_J	-40	150	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for Safe Operating parameters.

Table 3. ELECTRICAL CHARACTERISTICS $T_J = 25^{\circ}C$ unless otherwise noted

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
IGBT (T1, T2, T3)						
Collector-Emitter Cutoff Current	V _{GE} = 0 V, V _{CE} = 1200 V	I _{CES}	=	-	400	μΑ
Collector-Emitter Saturation Voltage	V _{GE} = 15 V, I _C = 80 A, T _J = 25°C	V _{CE(sat)}	=	- 400 μA 1.65 2 V 1.85 - 1.85 - 1.85 - 1.85 - 1.85 - 1.85 - 1.85 - 1.85 - 1.85 - 1.85 - 1.85 -		
	V _{GE} = 15 V, I _C = 80 A, T _J = 150°C		=	1.85	-	
Gate-Emitter Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 1.0 \text{ mA}$	V _{GE(TH)}	4.50	5.87	6.50	V
Gate Leakage Current	V _{GE} = 20 V, V _{CE} = 0 V	I _{GES}	=	-	800	nA
Turn-on Delay Time	T _J = 25°C	t _{d(on)}	=	13	-	ns
Rise Time	$V_{CE} = 800 \text{ V, } I_{C} = 50 \text{ A}$	t _r	=	22	-	
Turn-off Delay Time	VGE = +13 V, −9 V, ⊓G = 4.3 52	t _{d(off)}	-	262	_	
Fall Time	7	t _f	-	13	-	1
Turn-on Switching Loss per Pulse	7	E _{on}	-	1258	-	μJ
Turn off Switching Loss per Pulse	7	E _{off}	-	1277	-	1
Turn-on Delay Time	T _J = 125°C	t _{d(on)}	_	32	-	ns
Rise Time	$V_{CE} = 800 \text{ V}, I_{C} = 50 \text{ A}$	t _r	_	22	-	1
Turn-off Delay Time	V _{GE} = +15 V, −9 V, H _G = 4.3 Ω	t _{d(off)}	_	315	_	1
Fall Time	7	t _f	_	22	_	1
Turn-on Switching Loss per Pulse	7	E _{on}	_	1306	_	μJ
Turn off Switching Loss per Pulse	1	E _{off}	=	2221	=	
Input Capacitance	V _{CE} = 20 V, V _{GE} = 0 V, f = 10 kHz	C _{ies}	=	18151	_	pF
Output Capacitance	7	C _{oes}	=	345	=	1
Reverse Transfer Capacitance	7	C _{res}	=	294	=	1
Total Gate Charge	$V_{CE} = 600 \text{ V}, I_{C} = 25 \text{ A}, V_{GE} = \pm 15 \text{ V}$	Qg	=	817	-	nC
Thermal Resistance - chip-to-heatsink	Thermal grease,	R _{thJH}	=	0.60	=	°C/W
Thermal Resistance - chip-to-case	Thickness = 2 Mil $\pm 2\%$, $\lambda = 0.63$ W/mK	R _{thJC}	=	0.29	-	°C/W
PROTECTION DIODE (D11, D21, D31)	•	•		•		
Diode Forward Voltage	I _F = 30 A, T _J = 25°C	V_{F}	-	1.09	1.3	V
	I _F = 30 A, T _J = 150°C		=	0.99	-	
Thermal Resistance - chip-to-heatsink	Thermal grease,	R _{thJH}	=	1.60	-	°C/W
Thermal Resistance - chip-to-case	Thickness = 2 Mil $\pm 2\%$, λ = 0.63 W/mK	R _{thJC}	=	0.98	=	°C/W
SILICON CARBIDE BOOST DIODE (D12, I	D22, D32)					-
Diode Forward Voltage	I _F = 20 A, T _J = 25°C	V _F	=	1.48	1.75	V
	I _F = 20 A, T _J = 150°C	I _C = 80 A, T _J = 25°C				
Reverse Recovery Time	T _J = 25°C	t _{rr}	-	21	-	ns
Reverse Recovery Charge	$V_{CE} = 800 \text{ V}, I_{C} = 50 \text{ A}$	Q _{rr}	_	84	_	μC
Peak Reverse Recovery Current	$V_{GE} = +15 \text{ V}, -9 \text{ V}, H_{G} = 4.3 \Omega$	I _{RRM}	_	7	_	Α
Peak Rate of Fall of Recovery Current	1	di/dt	-	1750	_	A/μs
Reverse Recovery Energy	1	E _{rr}	_	65	_	μJ
Reverse Recovery Time	$I_F = 20 \text{ A}, T_J = 150^{\circ}\text{C}$ $T_J = 25^{\circ}\text{C}$ $V_{CE} = 800 \text{ V}, I_C = 50 \text{ A}$ $V_{GE} = +15 \text{ V}, -9 \text{ V}, R_G = 4.3 \Omega$ $T_J = 125^{\circ}\text{C}$	_	_	22	_	ns
Reverse Recovery Charge	V _{CE} = 800 V, I _C = 50 A		=	89	-	μC
Peak Reverse Recovery Current	$V_{GE} = +15 \text{ V}, -9 \text{ V}, R_{G} = 4.3 \Omega$	—	=	8	=	
Peak Rate of Fall of Recovery Current	1		=	1800	=	A/μs
Reverse Recovery Energy	1	E _{rr}	=	99	_	μJ

Table 3. ELECTRICAL CHARACTERISTICS T_{.1} = 25°C unless otherwise noted

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
SILICON CARBIDE BOOST DIODE (D12,	D22, D32)					•
Thermal Resistance - chip-to-heatsink	Thermal grease,	R_{thJH}	-	1.30	-	°C/W
Thermal Resistance - chip-to-case	Thickness = 2 Mil $\pm 2\%$, $\lambda = 0.63$ W/mK	R_{thJC}	-	0.85	-	°C/W
BYPASS DIODE (D13, D23, D33)						
Diode Forward Voltage	I _F = 50 A, T _J = 25°C	V_{F}	-	1.095	1.3	V
Flarent Decistores whin to heateigh	I _F = 50 A, T _J = 150°C		-	1.004	_	1
Thermal Resistance - chip-to-heatsink	Thermal grease,	R_{thJH}	-	1.40	-	°C/W
Thermal Resistance - chip-to-case	Thickness = 2 Mil $\pm 2\%$, $\lambda = 0.63$ W/mK	R _{thJC}	-	0.85	-	°C/W
THERMISTOR CHARACTERISTICS						
Nominal resistance	T = 25°C	R ₂₅	-	5	-	kΩ
Nominal resistance	T = 100°C	R ₁₀₀	-	493.3	_	Ω
Deviation of R25		ΔR/R	-5	=	5	%
Power dissipation		P_{D}	-	20	-	mW
Power dissipation constant			-	1.4	-	mW/K
B-value	B(25/50), tolerance ±2%		_	3375	_	K

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

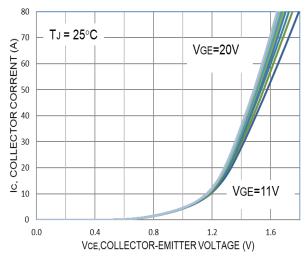
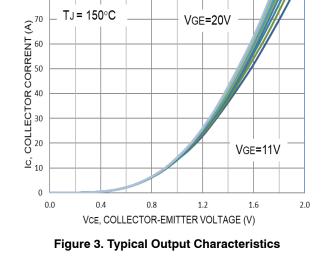


Figure 2. Typical Output Characteristics



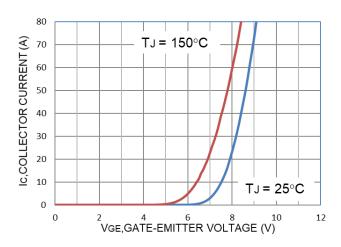


Figure 4. Typical Transfer Characteristics

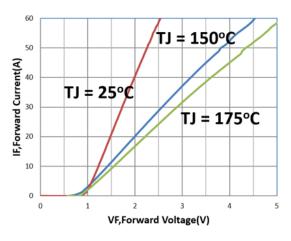


Figure 5. Diode Forward Characteristics

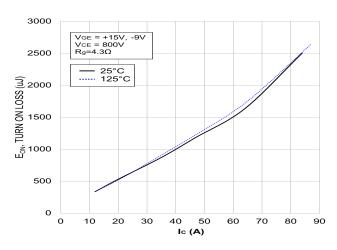


Figure 6. Typical Turn ON Loss vs. I_C

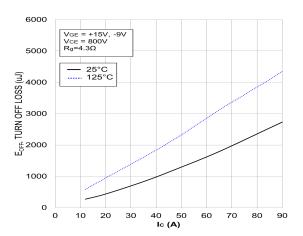


Figure 7. Typical Turn OFF Loss vs. I_C

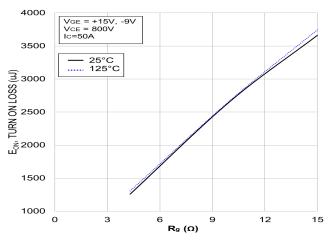


Figure 8. Typical Turn ON Loss vs. R_G

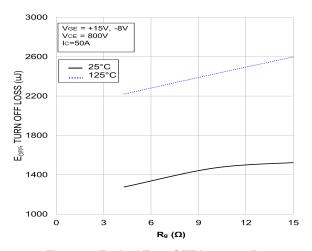


Figure 9. Typical Turn OFF Loss vs. R_G

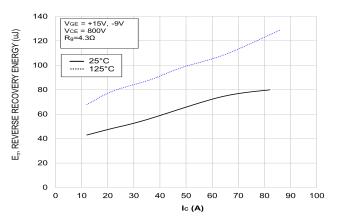


Figure 10. Typical Reverse Recovery Time vs. I_C

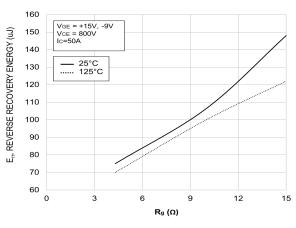


Figure 11. Typical Reverse Recovery Time vs. R_G

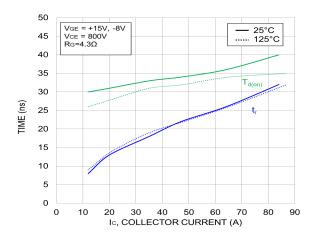


Figure 12. Typical Turn-On Switching Time vs. I_C

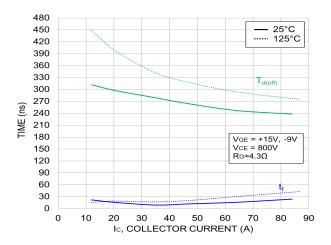


Figure 13. Typical Turn-Off Switching Time vs. I_C

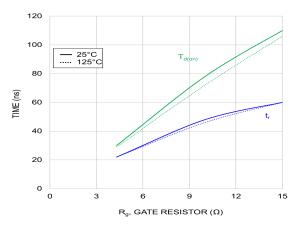


Figure 14. Typical Turn-On Switching Time vs. R_G

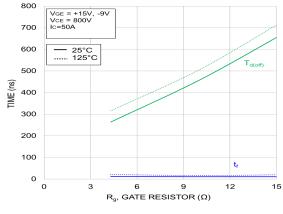


Figure 15. Typical Turn-Off Switching Time vs. R_G

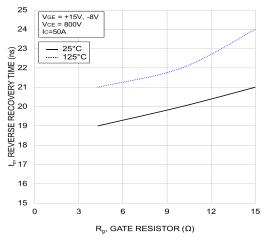


Figure 16. Typical Reverse Recovery Time vs. R_G

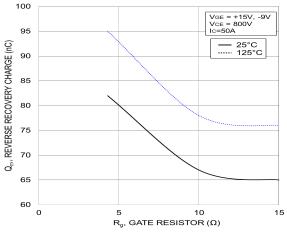


Figure 17. Typical Reverse Recovery Charge vs. R_G

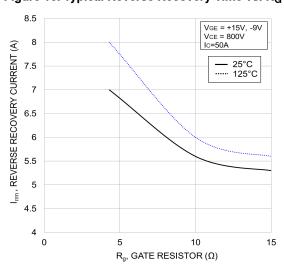


Figure 18. Typical Reverse Recovery Peak Current vs. R_G

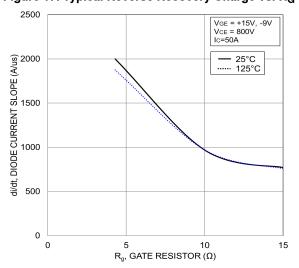


Figure 19. Typical di/dt vs. R_G

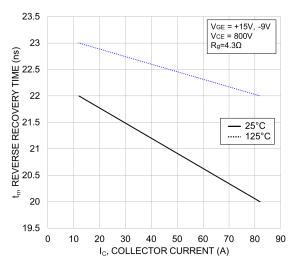


Figure 20. Typical Reverse Recovery Time vs. I_C

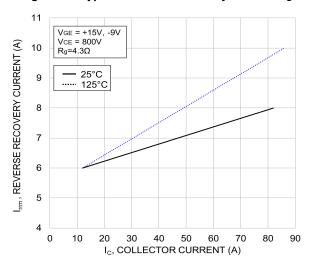


Figure 22. Typical Reverse Recovery Current vs. I_C

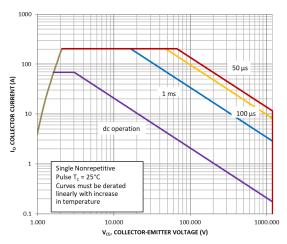


Figure 24. FBSOA

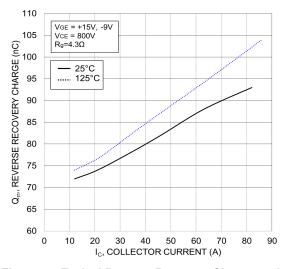


Figure 21. Typical Reverse Recovery Charge vs. I_C

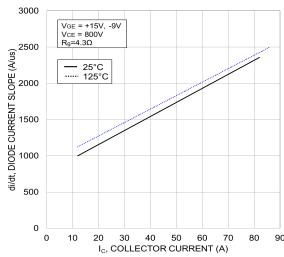


Figure 23. Typical di/dt Current Slope vs. I_C

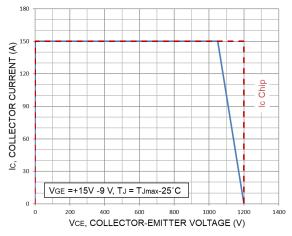


Figure 25. RBSOA

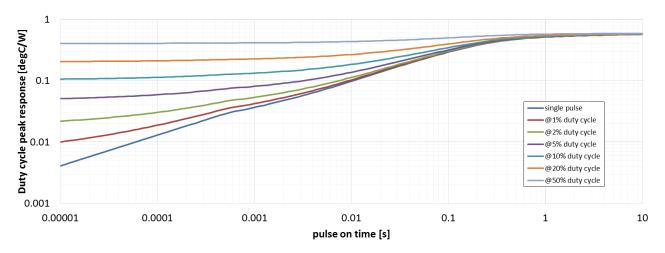


Figure 26. Transient Thermal Impedance (T1, T2, T3)

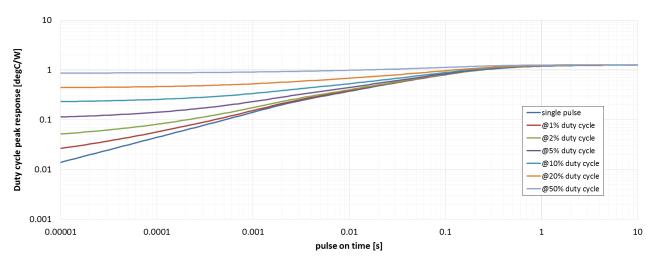


Figure 27. Transient Thermal Impedance (D12, D22, D32)

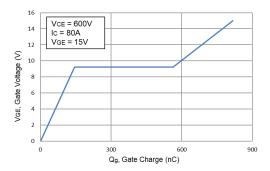


Figure 28. Gate Voltage vs. Gate Charge

TYPICAL CHARACTERISTICS - Diode (D13, D23, D33)

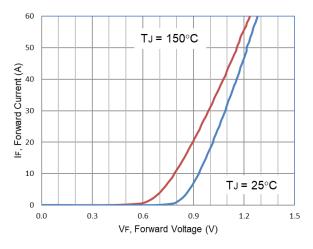


Figure 29. Diode Forward Characteristics

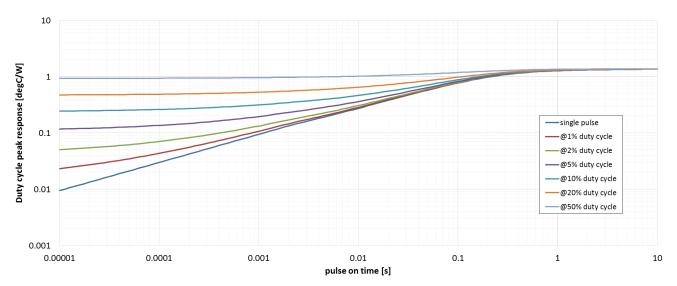


Figure 30. Transient Thermal Impedance

TYPICAL CHARACTERISTICS - Diode (D11, D21, D31)

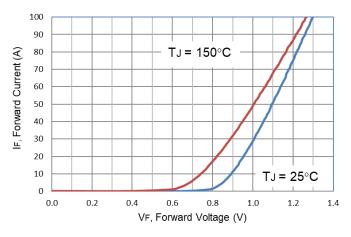


Figure 31. Diode Forward Characteristics

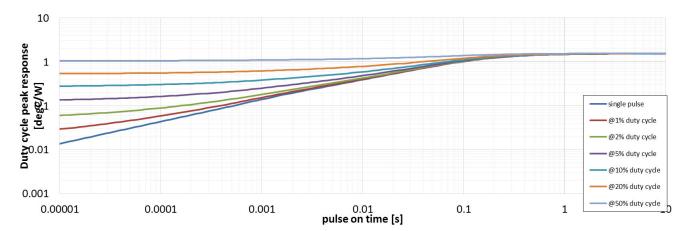


Figure 32. Transient Thermal Impedance

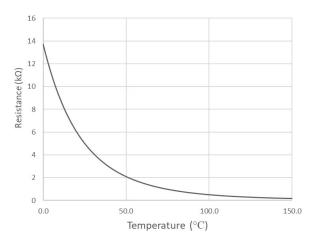


Figure 33. Thermistor Characteristic

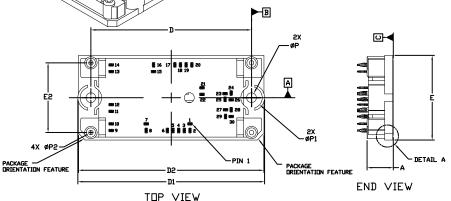
ORDERING INFORMATION

Orderable Part Number	Marking	Package	Shipping
NXH240B120H3Q1PG, NXH240B120H3Q1PG-R	NXH240B120H3Q1PG, NXH240B120H3Q1PG-R	Q1 BOOST, Case 180AX Press-fit Pins (Pb-Free)	21 Units / Blister Tray
NXH240B120H3Q1SG	NXH240B120H3Q1SG	Q1 BOOST, Case 180BQ Solder Pins (Pb-Free)	21 Units / Blister Tray

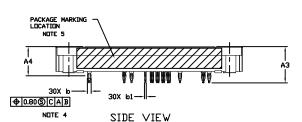


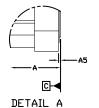


DATE 28 NOV 2017



MOUNTIN	MOUNTING HOLE POSITION		MOUNTIN	G HOLE P	OSITION
PIN	×	Υ	PIN	х	
1	8.30	11.55	16	-7.800	-14.50
2	8.30	14.50	17	1.60	-14.50
3	5.80	14.50	18	4.10	-14.50
4	3.30	14.50	19	6.60	-14.50
5	0.80	14.50	20	9.10	-14.50
6	-1.70	14.50	21	13.60	-4.40
7	-11.05	11.55	22	13.60	-1.45
8	-11.05	14.50	23	23.80	-1.80
9	-26.50	14.50	24	26.50	-2.05
10	-26.50	11.55	25	23.80	0170
11	-26.50	6.05	26	26.50	0.95
12	-26.50	3.05	27	24.00	5.30
13	-26.50	-11.55	28	26.50	5.30
14	-26.50	-14.50	29	24.00	8.30
15	-7.80	-11.55	30	26.50	8.30





NOTE 4

l 	71.00		
	•	000001	2X - Ø9.20 THRU HOLE
30X # Ø1.45 PLATED THRU HOLE		oooo arigin fo Hale lac IMENDED G PATTERN	OR MOUNTING ATIONS

	MILLIM	ETERS		
DIM	MIN.	NDM.		
Α	11.10	12.10		
АЗ	15.50	16.50		
A4	15.50 16.50 12.88 BSC			
A5	12.88 BSC 0.00 0.45 1.61 1.71			
b	1.61	1.71		
b1	0.75	0.85		
D	70.50	71.50		
D1	82.00	83.00		
D2	81.50	82.50		
E	36.90	37.90		
E2	30.30	31.30		
Р	4.30	4.50		
P1	9.30	9.70		
P2	1.90	2.10		

	PIN PI	NDITIZE	Ш		PIN P	NOITIE	
PIN	х	Υ		PIN	х	Y	
1	8.30	-11.55	П	16	-7.800	14.50	
2	8.30	-14.50	H	17	1.60	14.50	
3	5.80	-14.50	П	18	4.10	14.50	
4	3.30	-14.50	H	19	6.60	14.50	
5	0.80	-14.50	lĺ	20	9.10	14.50	
6	-1.70	-14.50	l	21	13.60	4.40	
7	-11.05	-11.55	lĺ	55	13.60	1.45	
8	-11.05	-14.50	l	23	23.80	1.80	
9	-26.50	-14.50	П	24	26.50	2.05	
10	-26.50	-11.55	l	25	23.80	-0.70	
11	-26.50	-6.05	H	26	26.50	-0.95	
12	-26.50	-3.05	١ſ	27	24.00	-5.30	
13	-26.50	11.55	H	28	26.50	-5.30	
14	-26.50	14.50	١ſ	29	24.00	-8.30	
15	-7.80	11.55	H	30	26.50	-8.30	

NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS

(VIEW FROM MOUNTING SIDE)

- 3. DIMENSIONS 6 AND 61 APPLY TO THE PLATED TERMINALS AND ARE MEASURED AT DIMENSION A4.
- 4. POSITION OF THE CENTER OF THE TERMINALS IS DETERMINED FROM DATUM B THE CENTER OF DIMENSION D, X DIRECTION, AND FROM DATUM A, Y DIRECTION. POSITIONAL TOLERANCE, AS NOTED IN DRAWING, APPLIES TO EACH TERMINAL IN BOTH DIRECTIONS.
- PACKAGE MARKING IS LOCATED AS SHOWN ON THE SIDE OPPOSITE THE PACKAGE ORIENTATION FEATURES.

GENERIC

MARKING DIAGRAM*

ATYYWW

XXXXX = Specific Device Code G = Pb-Free Package

AT = Assembly & Test Site Code YYWW = Year and Work Week Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

98AON07115G

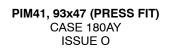
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DESCRIPTION: PIM30 71X37.4 (PRESS FIT)

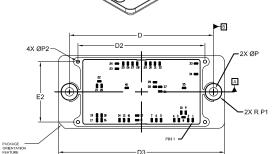
PAGE 1 OF 1

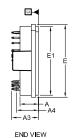
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DATE 19 MAR 2019





	MI	LIMETER	S
DIM	MIN.	NOM.	MAX.
Α	11.60	12.00	12.40
A1	4.40	4.70	5.00
A2	16.30	16.70	17.10
A3	16,90	17,30	17.70
A4	13.97	14.18	14.39
b	1.61	1.66	1.71
b1	0.75	0.80	0.85
D	92.90	93.00	93.10
D1	104.45	104.75	105.05
D2	81,80	82.00	82.20
D3	106.90	107.20	107.50
Е	46.70	47.00	47.30
E1	44.10	44.40	44.70
E2	38.80	39.00	39.20
Ρ	5,40	5,50	5,60
P1	5.15	5.35	5.55
P2	2,00	2,20	2,40

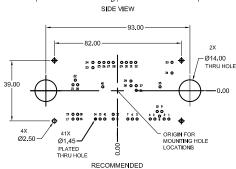
чο	Т	Е	S	٠	

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS 6 AND 61 APPLY TO THE PLATED TERMINALS AND ARE MEASURED AT DIMENSION A4.
- 4. POSITION OF THE CENTER OF THE TERMINALS AND MOUNTING HOLES IS DETERMINED FROM DATUM B THE CENTER OF DIMENSION D, X DIRECTION, AND FROM DATUM A, Y DIRECTION, POSITIONAL TOLERANCE AS NOTED IN DRAWING, APPLIES TO BOTH TERMINALS AND MOUNTING HOLES IN BOTH DIRECTIONS.
- PACKAGE MARKING IS LOCATED AS SHOWN ON THE SIDE OPPOSITE THE PACKAGE ORIENTATION FEATURES.
- 6 MOUNTING RECOMMENDATION IS SHOWN AS VIEWED FROM THE PCB TOP LAYER LOOKING DOWN TO SUBSEQUENT LAYERS.

	41X b		I1X b1	40
	M	Mana tana		A2
PACKAGE MARKING LOCATION			0	A1_
	•	D1——— SIDE VIEW		

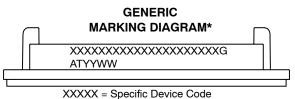
TOP VIEW

Ф 0.80**©** С А В



MOUNTING PATTERN

PIN X Y PIN X Y PIN X Y 1 33.15 -18.26 23 -15.86 14.90 2 30.15 -18.25 24 -15.86 18.25 3 24.15 -18.26 25 -11.75 18.25 4 21.15 -18.26 26 -8.76 18.25 5 12.65 -18.25 27 -5.75 18.25 6 9.65 -18.25 28 -2.76 18.25 7 6.65 -18.25 28 -2.76 18.25 8 27.15 -16.40 30 5.75 18.25 8 27.15 -16.40 31 8.76 18.25 10 25.65 -13.40 32 11.75 18.25 11 -2.75 -16.25 33 35.20 18.30 11.45 11 -2.75 -16.25 34 35.20 11.45 13 -11.20 -18.25 36 12.10 0.25 16 -2.570 -18.25 36 12.10 0.25 16 -2.570 -18.25 38 8.70 3.25 17 -2.870 -18.25 38 8.70 8.25 17 -2.870 -18.25 38 8.70 8.25 17 -2.870 -18.25 38 8.70 8.25 17 -2.870 -18.25 38 8.70 8.25 17 -2.870 -18.25 38 8.70 8.25 17 -2.870 -18.25 38 8.70 8.25 17 -2.870 -18.25 38 8.70 8.25 17 -2.870 -18.25 38 8.70 8.25 18 -2.50		PIN POSITION			PIN POSITION	
2 30.15 -18.26 24 -15.85 18.25 3 24.15 -18.26 25 -11.76 18.25 4 21.15 -18.26 26 -8.75 18.25 5 12.65 -18.26 27 -5.75 18.25 6 9.65 -18.26 28 -2.76 18.25 7 6.65 -18.26 29 2.75 18.25 8 27.15 -16.40 30 5.75 18.25 9 28.65 -13.40 31 8.76 18.25 10 25.65 -13.40 32 11.75 18.25 11 -2.75 -18.26 33 35.20 18.30 12 -2.75 -18.26 34 35.20 11.45 13 -11.20 -18.25 35 27.50 11.45 14 -14.20 -18.26 36 12.10 0.25 15 n/a n/a	PİN	Х	Υ	PIN	Х	Υ
3 24.15 18.25 25 11.75 18.25 4 21.15 18.25 26 8.75 18.25 5 12.65 18.25 27 5.75 18.25 6 9.65 18.25 28 2.75 18.25 7 6.65 18.25 29 2.75 18.25 8 27.15 16.40 30 5.75 18.25 18.25 19 28.65 13.40 30 15.75 18.25 10 25.65 13.40 32 11.75 18.25 11 2.75 18.25 33 35.20 18.30 11 2.75 18.25 11 2.75 18.25 35 27.50 18.25 11 1.27 18.25 35 27.50 18.25 11 1.27 18.25 35 27.50 2.80 11.45 13 11.20 18.25 35 27.50 2.50 14 1.420 18.25 36 12.10 3.25 15 16 2.57.00 18.25 38 8.70 3.25 17 2.8.70 18.25 38 8.70 3.25 17 2.8.70 18.25 38 8.70 3.25 17 2.8.70 18.25 38 8.70 6.25	1	33.15	-18.25	23	-15.85	14.90
4 21.15 -18.25 26 -8.75 18.25 5 12.65 -18.25 27 -5.75 18.25 6 9.65 -18.25 28 -2.75 18.25 7 6.65 -18.25 29 2.75 18.25 8 27.15 -16.40 30 5.75 18.25 9 28.65 -13.40 31 8.75 18.25 10 25.65 -13.40 32 11.75 18.25 11 -2.75 -18.25 33 35.20 18.30 12 -2.75 -15.25 34 35.20 11.40 13 -11.20 -18.25 36 12.10 0.25 14 -14.20 -18.25 36 12.10 0.25 15 n/a n/a 37 12.10 3.25 16 -2.5.70 -18.25 38 8.70 3.25 17 -2.8.70 -18.25 39 8.70 6.25 18 -2.5.70 -18.25 38 8.70 6.25 17 -2.8.70 -18.25 39 8.70 6.25 25 -5.70 -18.25 39 8.70 6.25 25 -5.70 -18.25 39 8.70 6.25 25 -5.70 -18.25 39 8.70 6.25 25 -5.70 -18.25 39 8.70 6.25 25 -5.70 -18.25 39 8.70 6.25 25 -5.70 -18.25 39 8.70 6.25 25 -5.70 -18.25 39 8.70 6.25 25 -5.70 -7.82 39 8.70 6.25 25 -5.70 -7.82 39 8.70 6.25 25 -7.70 -7.82 39 8.70 6.25 25 -7.70 -7.82 39 8.70 6.25 25 -7.70 -7.82 39 8.70 6.25	2	30.15	-18.25	24	-15.85	18.25
5 12.65 -18.26 27 -5.75 18.25 6 9.65 -18.25 28 -2.76 18.25 7 6.65 -18.26 29 2.75 18.25 8 27.15 -16.40 30 5.75 18.25 9 28.65 -13.40 31 8.76 18.25 10 25.65 -13.40 32 11.75 18.25 11 -2.75 -18.26 33 35.20 18.30 12 -2.75 -18.26 34 35.20 11.30 12 -1.75 -18.26 35 27.50 1.50 13 -11.20 -18.25 36 12.10 0.25 14 -14.20 -18.26 36 12.10 0.25 15 n/a n/a 37 12.10 3.25 16 -25.70 -18.25 38 8.70 3.25 17 -28.70 -18.25 <	3	24.15	-18.25	25	-11.75	18.25
6 9,65 -18,25 28 -2,75 18,25 7 6,65 18,25 29 27,5 18,25 8 27,15 -16,40 30 5,75 18,25 9 28,65 -13,40 31 8,76 18,25 10 25,65 -13,40 32 11,75 18,25 11 -2,75 -18,25 33 35,20 18,30 12 -2,75 -18,25 34 35,20 11,45 13 -11,20 -18,25 35 27,50 2,50 14 -14,20 -18,25 36 12,10 0,25 15 n/a n/a 37 12,10 0,25 16 -25,70 18,25 38 8,70 3,25 17 -28,70 -18,25 39 8,70 6,25	4	21.15	-18.25	26	-8.75	18.25
7 6.65 48.25 29 2.75 18.25 8 27.15 16.40 30 5.76 18.25 9 2.865 -13.40 31 8.75 18.25 10 25.65 -13.40 32 11.76 18.25 11 -2.75 -16.25 33 35.20 18.30 12 -2.75 -16.25 34 35.20 18.30 13 -11.20 18.25 35 27.50 2.50 14 -14.20 -18.25 36 12.10 0.25 15 n/a n/a 37 12.10 3.25 16 -2.570 18.25 38 8.70 3.25 17 -2.8.70 18.25 39 8.70 6.25	5	12.65	-18.25	27	-5.75	18.25
8 27.15 -16.40 30 5.75 18.25 9 28.65 -13.40 31 8.76 18.25 10 26.65 -13.40 32 11.78 18.25 11 -2.75 -18.28 33 35.20 18.30 12 -2.75 -18.26 34 35.20 11.43 13 -11.20 -18.25 35 27.50 1.2.50 14 -14.20 -18.26 36 12.10 0.25 15 n/a m/a 37 12.10 3.25 16 -25.70 -18.26 38 8.70 3.25 17 -28.70 -18.28 39 8.70 6.25	6	9.65	-18.25	28	-2.75	18.25
9 28.65 -13.40 31 8.75 18.25 10 25.65 -13.40 32 11.75 18.25 11 -2.75 -18.25 33 35.20 18.30 12 -2.75 -15.25 34 35.20 11.45 13 -11.20 -18.25 35 27.50 2.50 14 -14.20 18.25 36 12.10 0.25 15 n/a n/a 37 12.10 0.25 16 -2.57 0 18.25 38 8.70 3.25 17 -2.8.70 18.25 39 8.70 6.25	7	6.65	-18.25	29	2.75	18.25
10	8	27.15	-16.40	30	5.75	18.25
11 -2.75 -18.26 33 35.20 18.30 12 -2.75 -15.25 34 35.20 11.45 13 -11.20 -18.26 35 27.50 2.50 14 -14.20 -18.26 36 12.10 0.25 15 n/a m/a 37 12.10 3.25 16 -25.70 -18.26 38 8.70 3.25 17 -28.70 -18.25 39 8.70 6.25	9	28.65	-13.40	31	8.75	18.25
12 -2.75 -15.25 34 35.20 11.45 13 -11.20 -18.25 35 27.50 2.50 14 -14.20 -18.25 36 12.10 0.25 15 n/a n/a n/a 17 12.10 3.25 16 -25.70 -18.25 38 8.70 3.25 17 -28.70 -18.25 39 8.70 6.25	10	25.65	-13.40	32	11.75	18.25
13 -11.20 -18.25 35 27.50 2.50 14 -14.20 -18.25 36 12.10 0.25 15 n/a n/a 37 12.10 3.25 16 -25.70 -18.25 38 8.70 3.25 17 -28.70 -18.25 39 8.70 6.25	11	-2.75	-18.25	33	35.20	18.30
14 -14.20 -18.25 36 12.10 0.25 15 n/a n/a 37 12.10 3.25 16 -25.70 -18.25 38 8.70 3.25 17 -28.70 -18.25 39 8.70 6.25	12	-2.75	-15.25	34	35.20	11.45
15 n/a n/a 37 12.10 3.25 16 -25.70 -18.25 38 8.70 3.25 17 -28.70 -18.25 39 8.70 6.25	13	-11.20	-18.25	35	27.50	2.50
16 -25.70 -18.25 38 8.70 3.25 17 -28.70 -18.25 39 8.70 6.25	14	-14.20	-18.25	36	12.10	0.25
17 -28.70 -18.25 39 8.70 6.25	15	n/a	n/a	37	12.10	3.25
	16	-25.70	-18.25	38	8.70	3.25
40 25.70 45.25 40 0.50 2.50	17	-28.70	-18.25	39	8.70	6.25
10 23.70 13.23 40 9.30 2.30	18	-25.70	-15.25	40	-9.50	2.50
19 -28.70 -15.25 41 -8.20 -18.25	19	-28.70	-15.25	41	-8.20	-18.25
20 -25.70 3.85	20	-25.70	3.85			
21 -28,70 3,85	21	-28.70	3,85			
22 -27.20 6.85	22	-27-20	6.85			



G = Pb-Free Package
AT = Assembly & Test Site Code

YYWW = Year and Work Week Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

DESCRIPTION:	PIM41, 93x47 (PRESS FIT)		PAGE 1 OF 1	
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